# Reduction Rate of SiO<sub>2</sub> in Slag by Carbon-Saturated Iron

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The reduction rate of SiO<sub>2</sub> from CaO-SiO<sub>2</sub>-Al<sub>2</sub>O<sub>3</sub> and CaO-SiO<sub>2</sub>-Al<sub>2</sub>O<sub>3</sub>-TiO<sub>2</sub> slags by carbon-saturated iron melts was investigated over the temperature range 1350 °C to 1600 °C under an argon atmosphere. It was found that the reduction rate of silicon increased with increasing temperature and decreased with increasing ratio of CaO/SiO<sub>2</sub> in these slags. A kinetic analysis of the experimental results developed on the basis of the two film theory showed that the silicon transport rate from slag to metal phase was controlled by the rate of chemical reaction at the slag-metal interface. The rate constants obtained for the reaction were 10 g m<sup>-2</sup> s<sup>-1</sup> at 1550 °C. The apparent activation energy was 238.0 kJ mol<sup>-1</sup>.

# I. INTRODUCTION

**REDUCTION** of  $SiO_2$  from slag by carbon dissolved in iron melts occurs in the lower levels of the slag layer in a cupola where the FeO content of the slag is relatively low. Prediction of the silicon content of tapped liquid iron during the cupola melting process could be affected by silicon pickup due to this reaction when an iron droplet falls through the slag layer. Accurate measurements of silica reduction rates are an important aspect in the computer simulation of the cupola process.

As it is also one of most important reactions in blast furnace operation, the reduction of silica from CaO-Al<sub>2</sub>O<sub>3</sub>-SiO<sub>2</sub> slags by carbon in liquid iron has been studied by many investigators.<sup>[1-7]</sup> However, a considerable lack of agreement exists on the rate of the reaction. For example, the measured reaction rate, expressed as moles of  $SiO_2 m^{-2} s^{-1}$ , at 1600 °C for carbon-saturated iron and an activity of silica in the slag of 0.30 are scattered from  $9.17 \times 10^{-4[7]}$  to  $6.67 \times 10^{-3}$ .<sup>[4]</sup> Also, the rate-limiting step suggested by these investigations for silica reduction is not necessarily the same. However, it is generally agreed that the SiO<sub>2</sub> reduction reaction is a very slow reaction compared with the rates of other slag-metal reactions under similar conditions and that the reaction rate is strongly dependent on the temperature. The primary objective of this study was to determine the reaction rates at various conditions similar to those in a cupola and to determine the step or steps which control the rate of silica reduction.

#### **II. EXPERIMENTAL PROCEDURES**

An electric resistance furnace, as shown in Figure 1, was employed for heating and melting iron-carbon alloys in a graphite crucible. The reaction vessel was a vertical alumina tube of 60-mm ID and 1-m length. Both ends of the tube were closed with water-cooled brass caps, sealed with an O-ring, to prevent the oxidation of liquid iron by air. The temperature was measured with a thermocouple placed just below the graphite crucible in the homogeneous temperature zone (15-cm long) and was controlled to within  $\pm 0.5$  °C.

About 200 g of iron-carbon alloy was first melted in a graphite crucible (30-mm ID) under an argon atmosphere. After the experimental temperature was attained, about 25 g of slag were placed on the surface of the liquid iron. The instant the slag was fully melted (which took about 1 minute) was taken as the starting point of the reaction. The drop in temperature due to the addition of slag was about 10 °C, but the melt recovered to the set experimental temperature within 2 to 3 minutes. The reaction time for most of the experiments was 6 hours. Some metal samples (1 to 3 g) were withdrawn after each hour using a quartz tube, and slag samples (0.2 to 1 g) were taken by sticking slag to a stainless steel rod every 2 hours. Initial metal and slag samples were taken before the slag addition. The progress of the reaction was followed by chemical analysis of these metal and slag samples.

Electrolytic iron (Fe >99.9 pct) and electrode graphite (ash <0.1 pct) were used to prepare the iron-carbon alloy. Slags were prepared by premelting mixtures of desired quantities of CaCO<sub>3</sub>, SiO<sub>2</sub>, Al<sub>2</sub>O<sub>3</sub>, and TiO<sub>2</sub> reagents.

The slag compositions and temperatures of the experiments are summarized in Table I.

## **III. EXPERIMENTAL RESULTS**

The reduction rate of SiO<sub>2</sub> from CaO-SiO<sub>2</sub>-Al<sub>2</sub>O<sub>3</sub> or CaO-SiO<sub>2</sub>-Al<sub>2</sub>O<sub>3</sub>-TiO<sub>2</sub> slags by carbon-saturated iron was investigated using slags with the basicity (CaO/SiO<sub>2</sub>) varied from 0.82 to 1.42. The TiO<sub>2</sub> contents were varied from 0 to 4.75 pct. Temperatures were varied from 1350 °C to 1600 °C, and slag weights ranged from 25 to 75 g.

Figure 2 shows the change of silicon content in the metal and  $SiO_2$  content in the slag with time during run 2. It was found that the silicon content of the liquid iron increased linearly and the  $SiO_2$  content of the slag decreased linearly with reaction time at 1550 °C. The solid lines show the modeling prediction values. It was also found that the change of silicon content of the metal and that of the slag are stoichiometrically equal, which indicates that there was no SiO (g) formed as an intermediate product of the reaction which would leave the reaction system.

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Fig. 1-Schematic diagram of the experimental apparatus.

Table I. Experimental Conditions

Run No.	Temperature (°C)	Basicity (CaO/SiO <sub>2</sub> )	CaO	SiO <sub>2</sub>	Al <sub>2</sub> O <sub>3</sub> (Pct)	TiO <sub>2</sub>	Slag	Metal (Weight, g)
1	1550	0.82	35.0	42.6	20.8		25.0	201.0
2	1550	1.03	41.1	39.8	21.7		25.0	202.0
3	1550	1.42	42.4	29.8	19.6	4.67	25.0	202.0
4	1350	0.83	33.6	40.6	20.3	4.60	25.0	200.0
5	1450	0.78	33.4	42.7	18.5	4.75	25.0	199.9
6	1550	0.83	33.6	40.6	20.3	4.60	25.0	201.0
7	1600	0.83	33.6	40.6	20.3	4.60	24.9	199.9
8	1550	1.01	36.5	36.0	18.3	4.68	24.7	200.7
9	1550	1.00	38.1	38.1	19.0	4.75	75.0	201.0

Several experiments were carried out with the slag basicity (CaO/SiO<sub>2</sub>) varied from 0.82 to 1.42 at 1550 °C. As seen in Figure 3, the reduction rate of silicon decreased with increasing ratio of CaO/SiO<sub>2</sub> in the slag. It was found that the reduction rate of SiO<sub>2</sub> was proportional to the silica activity of the slag which is lower<sup>[8]</sup> for higher basicity slags.

The effect of temperature on the reduction rate of silica was examined using the slag with  $CaO/SiO_2 = 0.8$ and containing 20 pct  $Al_2O_3$  and 4.60 pct  $TiO_2$  in the temperature range of 1350 °C to 1600 °C. The results are shown in Figure 4. It is evident from this figure that the reduction rate of  $SiO_2$  is strongly dependent on the temperature, which indicates that the chemical reaction at the slag-metal interface is the rate-limiting step, or at least partly dominates the reaction rate of  $SiO_2$  reduction.

The effect of TiO<sub>2</sub> in the slag on silica reduction was also studied using a slag with CaO/SiO<sub>2</sub> = 1.0 and containing 20 pct Al<sub>2</sub>O<sub>3</sub> and 4.68 pct TiO<sub>2</sub> for comparison with the silicon reduction rate in the case without TiO<sub>2</sub> in the slag. As seen in Figure 5, the reduction rate of silicon is essentially independent of TiO<sub>2</sub> content in the slag when TiO<sub>2</sub> < 4.68 pct. The small difference in reaction rates between these two runs is considered to be the result of decreasing the SiO<sub>2</sub> content by addition of TiO<sub>2</sub> to the slag.

Kawai *et al.*<sup>[5]</sup> have studied the reduction rate of silica using graphite crucibles of different diameters. They found



Fig. 2—Change of silica content in slag and silicon content in metal with time at 1550  $^{\circ}$ C.



Fig. 3—Change of silicon content in the metal with time for various slag basicities at 1550 °C.

that the ratio of the slag/graphite to slag/metal interfacial area influences the reaction rate; *i.e.*, as the ratio increases, the rate of reduction increases. They explained that an increase in the slag-graphite area increases the silicon reduction rate, because an increase in an anode reaction rate (C (gr) +  $O^{2-} = CO + 2e^{-}$ ) at the slag-graphite interface enhances the cathode reaction  $(Si^{4+} + 4e^{-} = [Si])$  at the slag-metal interface. Pomfret and Grieveson<sup>[10]</sup> carried out experiments to test the influence of slag/graphite interfacial area, and they found that the reaction rate was independent of this parameter. To confirm this, the effect of slag-graphite area on silica reduction rate was studied using 25 and 75 g of slag in the present study. The slag-graphite area was calculated to be 12.9 and 38.8 cm<sup>2</sup>, respectively, using 2.57 g/cm<sup>3[11]</sup> for the slag density at 1550 °C. As seen in Figure 6, the reduction rate of silicon is independent



Fig. 4—Change of silicon content in metal with time for temperatures from 1350 °C to 1600 °C.



Fig. 5—Effect of TiO<sub>2</sub> in slag on the reduction rate of silicon at 1550 °C.

of the slag-graphite interface area and the contribution of an anode reaction to the silicon reduction rate is considered small and negligible for the present experimental condition. Thus, reaction is considered only to take place at the slag-metal interface in the present study.

## **IV. DISCUSSION**

The overall reaction of  $SiO_2$  reduction by carbon in liquid iron at the slag-metal interface can be expressed by

$$SiO_2 + 2C(gr) = Si + 2CO$$
 [1]

With a standard state of solid pure  $SiO_2$  for  $SiO_2$  in the slag, graphite for carbon in the metal, 1 wt pct silicon referred to infinite dilution for silicon in the metal,



Fig. 6—Effect of slag/graphite to slag/metal area ratios on the reduction rate of silica at 1550  $^{\circ}$ C.

and pure CO gas at 1 atm for CO gas, the free energy change for the reaction is

$$\Delta G^{\circ} = 566.5 - 0.3746T \, (\text{kJ})^{[12,13]}$$
[2]

$$\ln K_{\rm Si} = \ln \frac{a_{\rm SiO_2} P_{\rm CO}^2}{a_{\rm Si} a_{\rm C}^2} = -\frac{68,138}{T} + 45.06 \qquad [3]$$

The mechanism of this reaction is assumed to be through diffusion of silica in the bulk slag to the slagmetal interface where chemical Reaction [1] follows and then, in turn, is followed by diffusion of silicon from the interface into the bulk metal phase. The transport of carbon in the metal phase is considered not to be rate limiting, because the carbon content of the liquid iron is substantially larger than that of the silicon content and also because the diffusion coefficient of carbon is greater than that of silicon.

Using these assumptions, the process of silicon reduction can be described by the following relationships.

The rate of silicon transport in the slag phase is

$$\frac{d\,[\mathrm{Si}]}{dt} = \frac{A}{W_m} k_s \rho_s \left\{ (\mathrm{Si}) - (\mathrm{Si})^* \right\}$$
[4]

The rate of the chemical reaction at the slag-metal interface by the mass action law is

$$\frac{d [Si]}{dt} = \frac{A}{W_m} k_{Si} \left\{ a_C^2 a_{SiO_2}^* - \frac{a_{Si}^* P_{CO}^2}{K_{Si}} \right\}$$
[5]

where

$$a_{\rm SiO_2} = \gamma_{\rm SiO_2} N_{\rm SiO_2} = (\rm Si) \frac{\gamma_{\rm SiO_2}}{M_{\rm Si} \sum \frac{(\rm MO_n)}{M_{\rm MO_n}}}$$
[6]

$$a_{\rm Si} = f_{\rm Si}[\rm Si]$$
 [7]

$$\log f_{\rm Si} = e_{\rm Si}^{\rm C} \left[\rm C\right] + e_{\rm Si}^{\rm Si} \left[\rm Si\right]$$
[8]

$$e_{\rm Si}^{\rm C} = \frac{380}{T} - 0.023^{[14]}$$
 [9]

$$e_{\rm Si}^{\rm Si} = \frac{34.5}{T} + 0.089^{[12]}$$
 [10]

The rate of silicon transport in the metal phase is

$$\frac{d\,[Si]}{dt} = \frac{A}{W_m} k_m \rho_m \{[Si]^* - [Si]\}$$
[11]

. . . . .

Combining Eqs. [4], [5], and [11], the change of silicon content in the metal can be written as

$$\frac{d [Si]}{dt} = \frac{A}{W_m} \frac{(Si) - \frac{[Si]}{K'_{Si}a_c^2}}{\frac{1}{k_s \rho_s} + \frac{P_{CO}^2}{k_m \rho_m K'_{Si}a_c^2} + \frac{M_{Si} \sum \frac{(MO_n)}{M_{MO_n}}}{k_{Si}a_c^2 \gamma_{SiO_2}}}$$
[12]

where

$$K'_{\rm Si} = \left| \frac{[\rm Si] P_{\rm CO}^2}{(\rm Si) a_{\rm C}^2} \right|_{\rm eq} = K_{\rm Si} \frac{\gamma_{\rm SiO_2}}{f_{\rm Si} M_{\rm Si} \sum \frac{(\rm MO_n)}{M_{\rm MO_n}}} \quad [13]$$

The change of silicon content in the slag can be obtained using the following mass balance equation for silicon in the system

$$\frac{d\,[\mathrm{Si}]}{dt}\,W_m + \frac{d\,(\mathrm{Si})}{dt}\,W_s = 0 \qquad [14]$$

The values of  $\gamma_{SiO_2}$  in CaO-SiO<sub>2</sub>-Al<sub>2</sub>O<sub>3</sub> slags at 1550 °C and 1600 °C obtained by Rein and Chipman<sup>[8]</sup> were used in the present study. Values of  $\gamma_{SiO_2}$  at 1350 °C and 1450 °C were estimated by extrapolating their values at 1550 °C and 1600 °C. The value of  $K'_{Si}$  was then calculated using Eq. [13]. The interfacial area, A, was simply taken as the cross-sectional area of the crucible. Since the experiments utilized graphite crucibles, the activity of carbon in liquid iron is unity with reference to graphite. The pressure of CO gas generated at the slag-metal interface was considered to be one atmosphere.

The values of  $k_m \rho_m = 0.130 \text{ g cm}^{-2} \text{ s}^{-1}$  obtained by Mori *et al.*<sup>[15]</sup> and  $k_s \rho_s = 0.001 \text{ g cm}^{-2} \text{ s}^{-1}$  by Shinozaki *et al.*<sup>[16]</sup> were used for the mass transport coefficients of silicon in the metal and the slag phases. Since the chemical reaction at the interface is the rate-limiting step in the reduction of silica in slag by carbon in liquid iron, it is reasonable to neglect the effect of temperature and metal or slag compositions on the values of  $k_m \rho_m$  and  $k_s \rho_s$ .

The chemical reaction rate constants for silicon reduction by carbon in liquid iron,  $k_{\rm Si}$ , were determined by comparing the experimental results with the predictions from the rate Eq. [12], and they are shown in Table II. The solid lines in Figures 2 through 6 show the calculated silicon content in the metal and slag as a function of time using these values of  $k_{\rm Si}$ . As seen in

 Table II.
 Measured Reaction Rate, Rate Constant, Relative Resistances to

 Each Silicon Transport Step, and SiO2 Activities Calculated for Each Run

Run No.	Temperature (°C)	Basicity (CaO/SiO <sub>2</sub> )	Rate*	$k_{\rm Si}^{**}$	$k_{si}^{***}$		$R_m$ (Pct)	D	asio.	
	<u> </u>	(2007)2102)		(giii	3)	Λ	(FCI)	<u> </u>		YSiO <sub>2</sub>
1	1550	0.82	$1.05 \times 10^{-3}$	10.13	9.75	1.48	$3.2 \times 10^{-3}$	98.5	0.295	0.639
2	1550	1.03	$6.56 \times 10^{-4}$	10.98	10.67	0.99	$3.4 \times 10^{-3}$	99.0	0.170	0.418
3	1550	1.42	$2.06 \times 10^{-4}$	10.24	10.94	0.42	$3.2 \times 10^{-3}$	99.6	0.057	0.165
4	1350	0.83	$2.36 \times 10^{-4}$	1.76	1.76	0.35	$6.1 \times 10^{-3}$	99.6	0.377	0.823
5	1450	0.78	$4.47 \times 10^{-4}$	3.66	3.78	0.63	$1.1 \times 10^{-3}$	99.4	0.343	0.718
6	1550	0.83	$8.33 \times 10^{-4}$	8.11	8.02	1.23	$2.5 \times 10^{-3}$	98.8	0.293	0.639
7	1600	0.83	$2.00 \times 10^{-3}$	21.62	19.14	3.07	$2.4 \times 10^{-3}$	96.9	0.271	0.604
8	1550	1.01	$5.92 \times 10^{-4}$	9.62	9.61	0.99	$3.0 \times 10^{-3}$	99.0	0.175	0.418
9	1550	1.00	$6.06 \times 10^{-4}$	9.80	9.56	0.96	$3.0 \times 10^{-3}$	99.0	0.177	0.418
*mc **k <sub>si</sub> ***k <sub>si</sub>	the SiO <sub>2</sub> m <sup>-2</sup> s <sup>-1</sup> from Eq. [12] from Eq. [17]									

Table II, approximately the same values of  $k_{si}$  were obtained for the runs at 1550 °C.

According to the overall rate Eq. [12], the total resistance to the reaction is

$$R = \frac{1}{k_{s}\rho_{s}} + \frac{P_{CO}^{2}}{k_{m}\rho_{m}K_{Si}^{\prime}a_{C}^{2}} + \frac{M_{Si}\sum\frac{(MO_{n})}{M_{MO_{n}}}}{k_{Si}a_{C}^{2}\gamma_{SiO_{2}}}$$
[15]

The relative resistances of silicon transport in the slag  $(R_s, \text{pct})$  and silicon transport in the metal  $(R_m, \text{pct})$  and the chemical reaction at the slag-metal interface  $(R_c, \text{pct})$  are

$$R_{s} = \frac{100}{k_{s}\rho_{s}R}, \quad R_{m} = \frac{100P_{CO}^{2}}{k_{m}\rho_{m}K_{Si}^{\prime}a_{C}^{2}R},$$
  
and 
$$R_{c} = \frac{100M_{Si}\sum\frac{(MO_{n})}{M_{MO_{n}}}}{k_{Si}a_{C}^{2}\gamma_{SiO2}R}$$
[16]

respectively. The values for each experiment are shown in Table II. Comparing the values of the relative resistances to silicon transport in the slag ( $R_s = 0.3$  to 3 pct) or in the metal ( $R_m = 1.0$  to  $6.0 \times 10^{-3}$  pct), the relative resistance to chemical reaction at the slag-metal interface  $(R_c > 96 \text{ pct})$  is much larger. Thus, it is considered that the reduction rate of silicon is limited by the rate of the chemical reaction at the interface. This conclusion was also reached in the investigations by Turkdogan et al.,<sup>[1]</sup> Ashizuka et al.,<sup>[5]</sup> and Kawai et al.<sup>[9]</sup> However, other investigations have suggested a different controlling mechanism for SiO<sub>2</sub> reduction. For example, Rawling and Elliott<sup>[18]</sup> concluded that oxygen transport in the metal phase was the rate-controlling step in the temperature range of the present study (<1600 °C), but that above 1650 °C, mixed control between oxygen transport and chemical reaction at the metal-slag interface prevails.

Assuming the reduction rate of silicon is limited by the rate of the chemical reaction at the interface and ignoring the transport process of silicon in the slag and the metal and the effect of reversal of Reaction [1] because the silicon concentration is far below its equilibrium content with respect to the slag ([Si]<sub>eq</sub> = 16.0 to 19.0 pct<sup>[17]</sup> for runs at 1550 °C), the rate of silica reduction by carbonsaturated iron can be written as

$$\frac{d\,[\text{Si}]}{dt} = \frac{A}{W_m} k_{\text{Si}} a_{\text{SiO}_2}$$
[17]

The values of  $k_{\rm Si}$  obtained from experimental results according to this rate equation are also listed in Table II. The small differences between  $k_{\rm Si}$  derived from Eqs. [12] and [17] are caused by neglecting the transport processes for silicon in the slag and the metal and the effect of reversal of the reaction included in Eq. [17]. The value of  $k_{\rm Si}$  is approximately 10 g m<sup>-2</sup> s<sup>-1</sup> at 1550 °C.

Figure 7 shows the relationship between measured silica reduction rates and silica activity in the slag. A linear relationship is found between them, as predicted from theoretical considerations. The rates measured by Ashizuka *et al.*,<sup>[5]</sup> Kawai *et al.*,<sup>[9]</sup> and Rawling and Elliott<sup>[18]</sup> at 1550 °C are also shown in the figure for comparison with the results of the present study. The slope of the line obtained in the present study is higher than the other three.

Figure 8 shows the influence of temperature on  $k_{\rm Si}$ , which follows the Arrhenius equation. The apparent activation energy calculated from the slope is 238.0 kJ mol<sup>-1</sup>. This large apparent activation energy also supports the assumption that the rate-limiting step is chemical reaction at the interface.

## V. ESTIMATION OF SILICON PICKUP IN THE CUPOLA FURNACE

The rate of silicon reduction in the lower portion of the slag layer in a cupola where FeO is low has been calculated using the assumption of an Fe-C-Si alloy in the shape of a sphere immersed in a CaO-SiO<sub>2</sub>-Al<sub>2</sub>O<sub>3</sub> slag and a ratio of slag weight to metal weight of 10:1. The temperatures, slag, metal compositions, and iron droplet weight used in the calculations are presented in Table III.

The reaction rates were calculated using overall rate



Fig. 7—Variations in the reduction rate of silica by carbon-saturated iron as a function of the activity of silica in slag at 1500 °C.

Eq. [12], and the pressure of CO gas generated at the slag-metal interface was assumed to be 1 atm. The carbon content of the metal was calculated using a stoichiometric relationship between silicon and carbon content according to the following equation:

$$\frac{d\left[\mathrm{C}\right]}{M_{\mathrm{C}}\,dt} = -\frac{2d\left[\mathrm{Si}\right]}{M_{\mathrm{Si}}\,dt}$$
[18]

The carbon activity in liquid iron relative to graphite was calculated by

$$a_{\rm C} = \gamma_{\rm C} N_{\rm C} \qquad [19]$$

$$\ln \gamma_{\rm C} = \ln \gamma_{\rm C}^{\circ} + \varepsilon_{\rm C}^{\rm C} N_{\rm C} + \varepsilon_{\rm C}^{\rm Si} N_{\rm Si} \qquad [20]$$

$$\ln \gamma_{\rm C}^{\circ} = \frac{100 M_{\rm C}}{M_{\rm fe} R T} \Delta G_{\rm [pct C]}^{\circ}$$
[21]

$$\Delta G_{[\text{pct C}]}^{\circ} = 136.7 - 0.3674T \text{ kJ mol}^{-1[14]} \quad [22]$$

where  $\varepsilon_{\rm C}^{\rm C}$  and  $\varepsilon_{\rm C}^{\rm Si}$  were calculated from  $e_{\rm C}^{\rm C} = 0.195^{[19]}$ and  $e_{\rm C}^{\rm Si} = 162/T - 0.08^{[12]}$  The results of these calculations are presented in Table III and Figures 9 through 13.

Figure 9 shows the effect of carbon content in the alloy on the reaction rate at 1550 °C. An increase in carbon content in the metal increases the silicon pickup rate and the carbon loss rate. Figure 10 shows the effect of slag basicity on the reaction rate at 1550 °C. An increase in slag basicity decreases the silicon pickup rate and the carbon loss rate. Figure 11 shows the effect of temperature on the reaction rate. The silicon pickup rate and the carbon loss rate increase at higher temperatures. Figure 12 shows the effect of silicon content of the alloy on the reaction rate at 1550 °C. An increase of silicon content in the metal increases the silicon pickup rate and the carbon loss rate, because the carbon activity increases with increasing silicon content. Figure 13 shows the effect of droplet weight on the reaction rate at 1550 °C. A decrease in the droplet size increases the silicon pickup rate and the carbon loss rate, because the ratio of surface area to metal weight is larger for a smaller droplet.

However, as seen in Table III and Figures 9 through 13, the values of rate of silicon or carbon content changes are small, which means that this reaction is not of great importance in cupola operations.

## **VI. CONCLUSIONS**

The reduction rate of SiO<sub>2</sub> from CaO-SiO<sub>2</sub>-Al<sub>2</sub>O<sub>3</sub> or CaO-SiO<sub>2</sub>-Al<sub>2</sub>O<sub>3</sub>-TiO<sub>2</sub> slags by carbon-saturated iron was investigated using slags with the basicity (CaO/SiO<sub>2</sub>) varied from 0.82 to 1.42. The TiO<sub>2</sub> content of the slags was varied at 0 and 4.75 pct. The temperature was varied from 1350 °C to 1600 °C. The low reaction rate and relatively high activation energy of the SiO<sub>2</sub> reduction suggest that the chemical reaction at the slags-metal interface is the slowest step in the overall reaction. A kinetic model for reduction of SiO<sub>2</sub> in slags by Fe-C alloys was developed based on the experimental results. The

Table III. Model Calculation Conditions and Calculated Reaction Rates

Cal No.	Iron Droplet Type	(g)	Slag*	Temperature (°C)	$\frac{k_{\rm Si}}{({\rm g \ m^{-2} \ s^{-1}})}$	$\Delta$ [Pct C]/ $\Delta t$ (s <sup>-</sup>	$\Delta$ [Pct Si]/ $\Delta t$
	 2C-Fe	1	A	1550	10.13	$-0.48 \times 10^{-5}$	$0.57 \times 10^{-5}$
Cal-2	3C-Fe	1	Α	1550	10.13	$-2.32 \times 10^{-5}$	$2.70 \times 10^{-5}$
Cal-3	4C-Fe	1	Α	1550	10.13	$-8.27 \times 10^{-5}$	$9.67 \times 10^{-5}$
Cal-4	C(sat)-Fe	1	Α	1550	10.13	0	$4.10 \times 10^{-4}$
Cal-5	4C-Fe	1	В	1550	10.13	$-4.90 \times 10^{-5}$	$5.73 \times 10^{-5}$
Cal-6	4C-Fe	1	С	1550	10.13	$-1.78 \times 10^{-5}$	$2.10 \times 10^{-5}$
Cal-7	4C-Fe	1	Α	1350	1.76	$-2.32 \times 10^{-5}$	$2.72 \times 10^{-5}$
Cal-8	4C-Fe	1	Α	1450	3.78	$-3.82 \times 10^{-5}$	$4.47 \times 10^{-5}$
Cal-9	4C-Fe	1	Α	1600	21.62	$-1.67 \times 10^{-4}$	$1.95 \times 10^{-4}$
Cal-10	4C-1Si-Fe	1	Α	1550	10.13	$-1.07 \times 10^{-4}$	$1.24 \times 10^{-4}$
Cal-11	4C-2Si-Fe	1	Α	1550	10.13	$-1.37 \times 10^{-4}$	$1.61 \times 10^{-4}$
Cal-12	4C-3Si-Fe	1	Α	1550	10.13	$-1.77 \times 10^{-4}$	$2.07 \times 10^{-4}$
Cal-13	4C-Fe	0.5	Α	1550	10.13	$-1.04 \times 10^{-4}$	$1.22 \times 10^{-4}$
Cal-14	4C-Fe	2	Α	1550	10.13	$-6.55 \times 10^{-5}$	$7.68 \times 10^{-5}$
*Slag A: $35CaO-45SiO_2-20Al_2O_3$ , $CaO/SiO_2 = 0.78$							

Slag B:  $40CaO - 40SiO_2 - 20Al_2O_3$ ,  $CaO/SiO_2 = 1.00$ 

Slag C:  $45CaO-35SiO_2-20Al_2O_3$ , CaO/SiO<sub>2</sub> = 1.29



Fig. 8—Arrhenius plot for the rate constant  $k_{si}$  of silica reduction in slags by carbon-saturated iron.



Fig. 9—Effect of carbon content of the alloy on the reaction rate at 1550 °C: (a) change of silicon content of metal with time and (b) change of carbon content of metal with time.



Fig. 10—Effect of slag basicity on the reaction rate at 1550 °C: (a) change of silicon content of metal with time and (b) change of carbon content of metal with time.



Fig. 11—Effect of temperature on the reaction rate of silica in slag A: (a) change of silicon content of metal with time and (b) change of carbon content of metal with time.



Fig. 12—Effect of silicon content of the alloy on the reaction rate at 1550 °C: (a) change of silicon content of metal with time and (b) change of carbon content of metal with time.



Fig. 13—Effect of droplet weight on the reaction rate at 1550 °C: (a) change of silicon content of metal with time and (b) change of carbon content of metal with time.

reduction rate was proportional to the silica activity in the slag, and the rate constant was approximately  $10 \text{ g m}^{-2} \text{ s}^{-1}$  at 1550 °C. The silicon transport rate from the slag to the metal is controlled by the rate of the chemical reaction at the slag-metal interface. The apparent activation energy for the reduction reaction is 238.0 kJ mol<sup>-1</sup>. The silicon pickup and the carbon loss by the silica reduction reaction in a cupola are relatively small considering the short time of droplet contact with slag and the low reaction rate.

## NOMENCLATURE

Α	reaction area, m <sup>2</sup>
<i>a</i>	activity of cilicon

- activity of silicon in metal  $a_{\underline{S}\underline{i}}$  $e_{\rm Si}^{\rm C}$
- interaction parameter between carbon and silicon in metal
- $e_{\rm Si}^{\rm Si}$ self-interaction parameter of silicon in metal activity coefficient of silicon in metal
- $f_{\mathrm{Si}} \Delta G^{\circ}$ free energy of the reaction at standard state,  $J \text{ mol}^{-1}$
- $\Delta G^0_{\mathrm{[pct C]}}$ free energy change of carbon dissolution in iron. J mol<sup>-1</sup>
- equilibrium constant of Reaction [1]
- K<sub>Si</sub> K'<sub>Si</sub> apparent equilibrium constant of Reaction [1]
- k<sub>m</sub> mass transfer coefficient in metal, m s
- mass transfer coefficient in slag, m  $s^{-1}$ k<sub>s</sub>
- rate constant of Reaction [1],  $g m^{-2} s^{-1}$  $k_{Si}$
- $(MO_{n})$ weight percent of oxide (CaO, SiO<sub>2</sub>, Al<sub>2</sub>O<sub>3</sub>, and  $TiO_2$ ) in slag
- $M_{MO_n}$ molecular weight of oxide (CaO, SiO<sub>2</sub>, Al<sub>2</sub>O<sub>3</sub>, and TiO<sub>2</sub>), g mol<sup>-</sup>
- $M_{\rm Si}$ molecular weight of silicon,  $g \text{ mol}^{-1}$
- $N_{\rm C}$ mole fraction of carbon in metal
- $P_{\rm CO}$ pressure of CO, atm
- [Si] content of silicon in metal, wt pct
- (Si) content of silicon in slag, wt pct
- Т temperature, K
- reaction time, s t
- $W_{n}$ metal weight, g
- $W_{s}$ slag weight, g
- activity coefficient of SiO<sub>2</sub> in slag  $\gamma_{SiO_2}$
- activity coefficient of carbon in metal by  $\gamma_{\rm C}$ Raoult's law
- $\gamma_{\rm C}^0$ activity coefficient of carbon at infinite dilution by Raoult's law

- $\epsilon_{\rm C}^{\rm C}$ self-interaction coefficient of carbon in metal
- $\varepsilon_{\rm C}^{\rm Si}$ interaction coefficieent between silicon and carbon in metal
- metal density, kg  $m^{-3}$  $\rho_m$
- slag density, kg m<sup>-3</sup>  $\rho_s$

## Superscript and Subscript

indicates equilibrium eq indicates quantity at surface

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